

Medium power transistor (−32V, −2A)

2SB1188 / 2SB1182 / 2SB1240

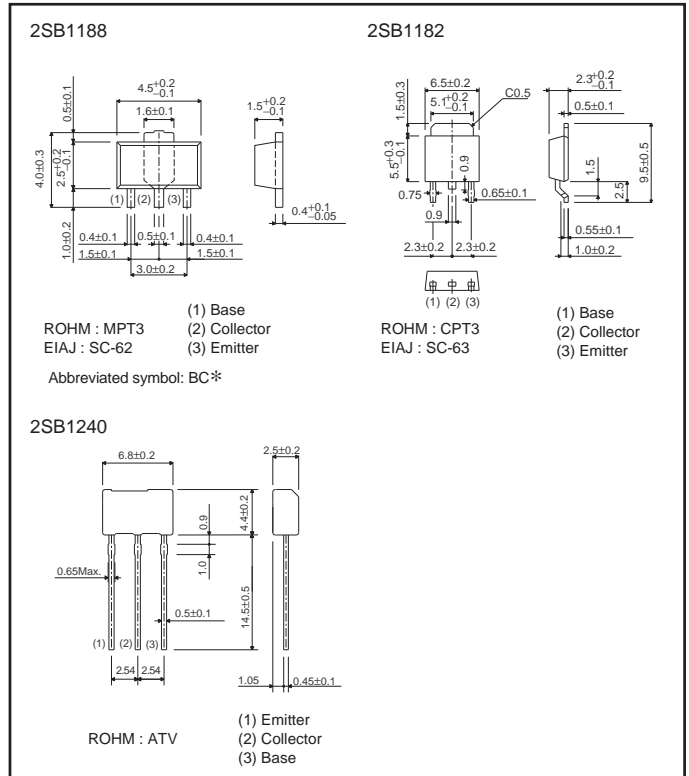
●Features

- 1) Low $V_{CE(sat)}$.
 $V_{CE(sat)} = -0.5V$ (Typ.)
 $(I_C/I_B = -2A / -0.2A)$
- 2) Complements the 2SD1766 / 2SD1758 / 2SD1862.

●Structure

Epitaxial planar type
PNP silicon transistor

●Dimensions (Unit : mm)



* Denotes h_{FE}

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	-40	V
Collector-emitter voltage	V_{CEO}	-32	V
Emitter-base voltage	V_{EBO}	-5	V
Collector current	I_C	-2	A(DC)
		-3	A (Pulse)*1
Collector power dissipation	P_C	0.5	W
		2	W *2
		10	W (Tc=25°C)
	2SB1240	1	W *3
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 to 150	°C

*1 Single pulse, $P_w=100ms$

*2 When mounted on a 40×40×0.7 mm ceramic board.

*3 Printed circuit board, 1.7mm thick, collector copper plating 100mm² or larger.

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV _{CB0}	-40	-	-	V	I _C =-50μA
Collector-emitter breakdown voltage	BV _{CEO}	-32	-	-	V	I _C =-1mA
Emitter-base breakdown voltage	BV _{EBO}	-5	-	-	V	I _E =-50μA
Collector cutoff current	I _{CB0}	-	-	-1	μA	V _{CB} =-20V
Emitter cutoff current	I _{EBO}	-	-	-1	μA	V _{EB} =-4V
Collector-emitter saturation voltage	V _{CE(sat)}	-	-0.5	-0.8	V	I _C /I _B =-2A/-0.2A
DC current transfer ratio	h _{FE}	120	-	390	-	V _{CE} =-3V, I _C =-0.5A
Transition frequency	f _T	-	100	-	MHz	V _{CE} =-5V, I _E =0.5A, f=100MHz
Output capacitance	C _{ob}	-	50	-	pF	V _{CB} =-10V, I _E =0A, f=1MHz

* Measured using pulse current.

●Packaging specifications and h_{FE}

Type	h _{FE}	Package	Taping		
		Code	T100	TL	TV2
		Basic ordering unit (pieces)	1000	2500	2500
2SB1188	QR	○	-	-	-
2SB1182	QR	-	○	-	-
2SB1240	QR	-	-	○	-

h_{FE} values are classified as follows :

Item	Q	R
h _{FE}	120 to 270	180 to 390

●Electrical characteristic curves

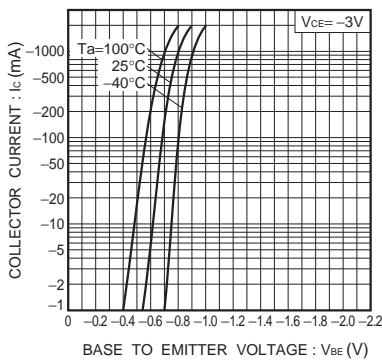


Fig.1 Grounded emitter propagation characteristics

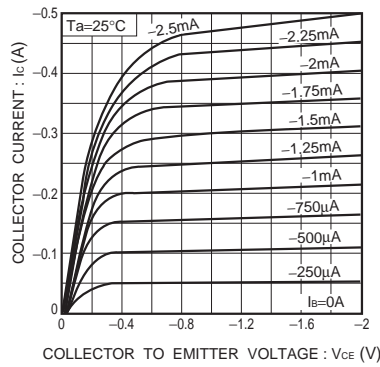


Fig.2 Grounded emitter output characteristics

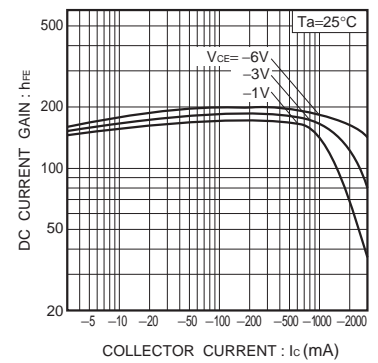


Fig.3 DC current gain vs. collector current (I)

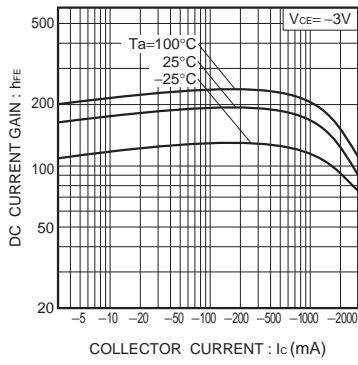


Fig.4 DC current gain vs. collector current (II)

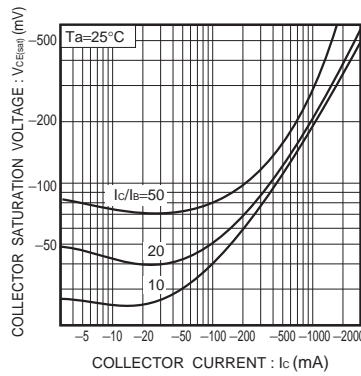


Fig.5 Collector-emitter saturation voltage vs. collector current (I)

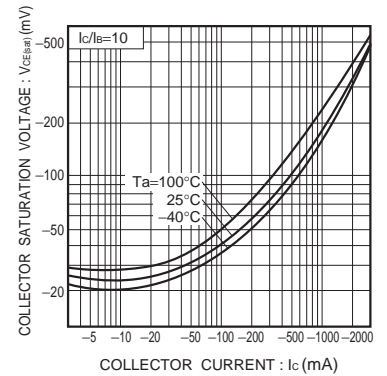


Fig.6 Collector-emitter saturation voltage vs. collector current (II)

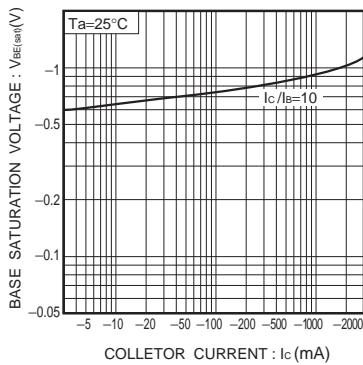


Fig.7 Base-emitter saturation voltage vs. collector current

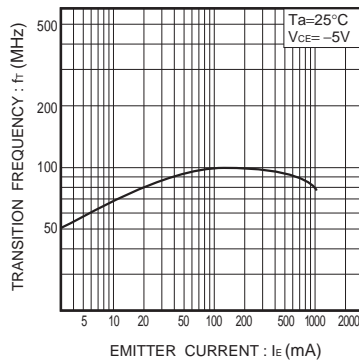


Fig.8 Gain bandwidth product vs. emitter current

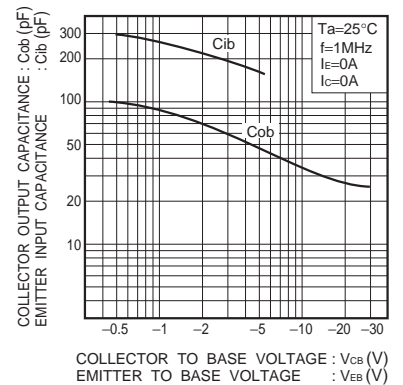


Fig.9 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

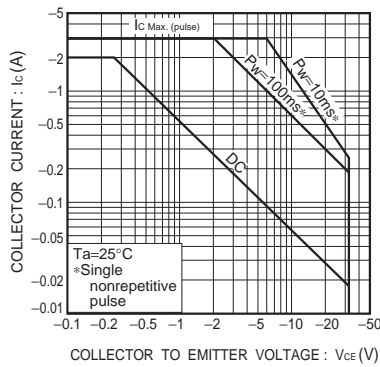


Fig.10 Safe operation area (2SB1188)

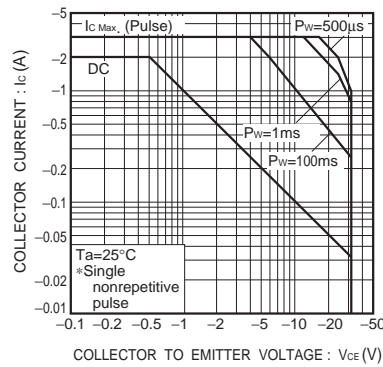


Fig.11 Safe operation area (2SB1182)

Notes

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